### CD74FCT623 BICMOS OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS SCBS736 - JULY 2000

•	BiCMOS Technology With Low Quiescent Power	E, M, OR SM PACKAGE (TOP VIEW)				
٠	Buffered Inputs		20 V <sub>CC</sub>			
•	Noninverted Outputs	A1 [] 2	19 OEBA			
•	Input/Output Isolation From V <sub>CC</sub>	A2 🛿 3	18 B1			
•	Controlled Output Edge Rates	A3 🛛 4	17 B2			
•	64-mA Output Sink Current		16 B3			
•	Output Voltage Swing Limited to 3.7 V	A5 [] 6 A6 [] 7	15 B4 14 B5			
•	SCR Latch-Up-Resistant BiCMOS Process	A7 🛿 8	13 🛛 B6			
	and Circuit Design	A8 🛿 9	12 🛛 B7			
•	Package Options Include Plastic Small-Outline (M) and Shrink Small-Outline (SM) Packages and Standard Plastic (E) DIP	GND [10	11 B8			

### description

The CD74FCT623 is an octal bus transceiver that uses a small-geometry BiCMOS technology. The output stage is a combination of bipolar and CMOS transistors that limits the output high level to two diode drops below  $V_{CC}$ . This resultant lowering of output swing (0 V to 3.7 V) reduces power-bus ringing [a source of electromagnetic interference (EMI)] and minimizes  $V_{CC}$  bounce and ground bounce and their effects during simultaneous output switching. The output configuration also enhances switching speed and is capable of sinking 64 mA.

This device is a noninverting, 3-state, bidirectional transceiver-buffer intended for two-way transmission from A bus to B bus or B bus to A bus, depending on the logic levels of the output-enable (OEAB, OEBA) inputs.

The dual output-enable provision gives these devices the capability to store data by simultaneously enabling OEAB and OEBA. Each output reinforces its input under these conditions, and when all other data sources to the bus lines are at high impedance, both sets of bus lines remain in their last states.

The CD74FCT623 is characterized for operation from 0°C to 70°C.

TONOTION TABLE								
INP	UTS							
OEBA	OEAB	OPERATION						
L	L	B data to A bus						
н	Н	A data to B bus						
н	L	Isolation <sup>†</sup>						
L	Н	B data to A bus, A data to B bus						

### FUNCTION TABLE

<sup>†</sup> To prevent excess current in the high-impedance (isolation) state, all I/O terminals should be terminated with  $10-k\Omega$  to  $1-M\Omega$  resistors.



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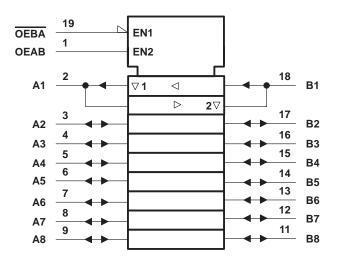
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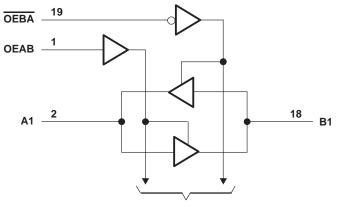
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### logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## logic diagram (positive logic)



**To Seven Other Transceivers** 



## CD74FCT623 BICMOS OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

DC supply voltage range, $V_{CC}$ . DC input clamp current, $I_{IK}$ ( $V_{I} < -0.5 V$ ) DC output clamp current, $I_{OK}$ ( $V_{O} < -0.5 V$ ) DC output sink current per output pin, $I_{OL}$ . DC output source current per output pin, $I_{OH}$ . Continuous current through $V_{CC}$ , $I_{CC}$ . Continuous current through GND Package thermal impedance, $\theta_{JA}$ (see Note 1): E package . M package	20 mA 50 mA 50 mA 30 m
SM package	
in the second sig	

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51.

### recommended operating conditions (see Note 2)

		MIN	MAX	UNIT
Vcc	Supply voltage	4.75	5.25	V
VIH	High-level input voltage	2		V
VIL	Low-level input voltage		0.8	V
VI	Input voltage	0	VCC	V
Vo	Output voltage	0	VCC	V
ЮН	High-level output current		-15	mA
IOL	Low-level output current		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	10	ns/V
Т <sub>А</sub>	Operating free-air temperature	0	70	°C

NOTE 2: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

## electrical characteristics over recommended operating temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vaa	T <sub>A</sub> = 25°C	MIN MAX	UNIT
PARAMETER	TEST CONDITIONS	Vcc	MIN MAX		UNIT
VIK	lj = -18 mA	4.75 V	-1.2	-1.2	V
VOH	I <sub>OH</sub> = –15 mA	4.75 V	2.4	2.4	V
VOL	I <sub>OL</sub> = 64 mA	4.75 V	0.55	0.55	V
li	$V_I = V_{CC}$ or GND	5.25 V	±0.1	±1	μΑ
I <sub>OZ</sub>	$V_{O} = V_{CC}$ or GND	5.25 V	±0.5	±10	μΑ
los‡	$V_{I} = V_{CC} \text{ or GND}, \qquad V_{O} = 0$	5.25 V	-60	-60	mA
ICC	$V_{I} = V_{CC} \text{ or GND}, \qquad I_{O} = 0$	5.25 V	8	80	μΑ
∆I <sub>CC</sub> §	One input at 3.4 V, Other inputs at $V_{CC}$ or GND	5.25 V	1.6	1.6	mA
Ci	$V_{I} = V_{CC} \text{ or } GND$		10	10	pF
Co	$V_{O} = V_{CC} \text{ or } GND$		15	15	pF

<sup>‡</sup>Not more than one output should be tested at a time, and the duration of the test should not exceed 100 ms.

§ This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V<sub>CC</sub>.



### **CD74FCT623 BICMOS OCTAL BUS TRANSCEIVER** WITH 3-STATE OUTPUTS SCBS736 - JULY 2000

# switching characteristics over recommended operating conditions (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	T <sub>A</sub> = 25°C	MIN	MAX	UNIT
PARAMETER	(INPUT)	(OUTPUT)	TYP		IVIAA	UNIT
<sup>t</sup> pd	A or B	B or A	5.3	1.5	7	ns
	OEBA	А	7.1	1.5		
ten	OEAB	В	7.1	1.5	9.5	ns
<b>4</b>	OEBA	А	5.6	1.5	7.5	200
<sup>t</sup> dis	OEAB	В	5.6	1.5	7.5	ns

## noise characteristics, V<sub>CC</sub> = 5 V, C<sub>L</sub> = 50 pF, T<sub>A</sub> = 25°C

	PARAMETER	MIN	TYP	MAX	UNIT
VOL(P)	Quiet output, maximum dynamic V <sub>OL</sub>		1		V
VOH(V)	Quiet output, minimum dynamic V <sub>OH</sub>		0.5		V
VIH(D)	High-level dynamic input voltage	2			V
V <sub>IL(D)</sub>	Low-level dynamic input voltage			0.8	V

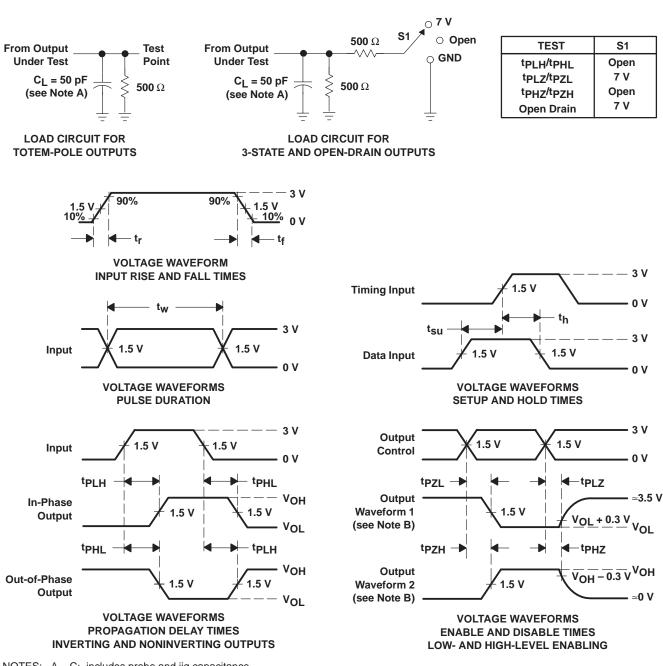
## operating characteristics, $T_A = 25^{\circ}C$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub> Power dissipation capacitance	No load, f = 1 MHz	48	pF



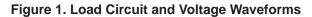
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PARAMETER MEASUREMENT INFORMATION

- NOTES: A. CL includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics:  $PRR \le 1$  MHz,  $Z_O = 50 \Omega$ ,  $t_f$  and  $t_f = 2.5$  ns. D. The outputs are measured one at a time with one input transition per measurement.
  - D. The outputs are measured one at a ti
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G.  $t_{PHL}$  and  $t_{PLH}$  are the same as  $t_{pd}$ .







11-Apr-2013

## PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
CD74FCT623M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	74FCT623M	Samples
CD74FCT623ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	74FCT623M	Samples
CD74FCT623MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	74FCT623M	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



## LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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